

## EAST Search History

| Ref # | Hits   | Search Query   | DBs   | Default Operator | Plurals | Time Stamp       |
|-------|--------|--|---|------------------|---------|------------------|
| L1    | 0      | Van-den-meerakker.in.  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:40 |
| L2    | 0      | (Van-den-meerakker.in.)  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:41 |
| L3    | 0      | (blaaderen-alfons.in.)   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:41 |
| L4    | 0      | (carlos-maria-van-kats.in.)                                      | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:41 |
| L5    | 474739 | (Van den meerakker.in.)  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:42 |
| L6    | 31     | (meerakker.in.)  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 13:42 |
| S1    | 2059   | nanowires  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 05:55 |
| S2    | 1272   | nanowires and semiconductor                                      | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/28 12:00 |
| S3    | 245    | nanowires and semiconductor and dispersion                       | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/28 12:00 |
| S4    | 87     | (@ad<="20021118") and nanowires and semiconductor and dispersion | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR               | ON      | 2006/03/29 08:48 |

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|-----|-----|--|---|----|----|------------------|
| S5  | 53  | (@ad<="20021118") and nanowires and semiconductor and dispersion and etch\$4   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 12:02 |
| S6  | 28  | (@ad<="20021118") and nanowires and semiconductor and dispersion and etch\$4 and mask  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 12:02 |
| S7  | 28  | (@ad<="20021118") and nanowires and semiconductor and dispersion and etch\$4 and mask  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 13:48 |
| S8  | 0   | (@ad<="20021118") and (manufacturing adj nanowires) and semiconductor and dispersion and etch\$4 and mask                    | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 12:16 |
| S9  | 0   | (@ad<="20021118") and (manufactur\$4 with nanowires) and semiconductor and dispersion and etch\$4 and mask                   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 12:16 |
| S10 | 145 | (@ad<="20021118") and nanowires and semiconductor and etch\$4 and mask   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 14:13 |
| S11 | 75  | (@ad<="20021118") and nanowires and semiconductor and etch\$4 and mask and anod\$4   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 16:42 |
| S12 | 16  | (@ad<="20021118") and nanowires and semiconductor and etch\$4 and mask and anodically  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 16:42 |
| S13 | 3   | (@ad<="20021118") and nanowires and semiconductor and etch\$4 and mask and (anodically with etch\$4)                         | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 16:44 |
| S14 | 35  | (@ad<="20021118") and nanowires and semiconductor and etch\$4 and mask and ((anodically or electrochemical\$4) with etch\$4) | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 17:20 |

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|     |     |  |   |    |    |                  |
|-----|-----|--|---|----|----|------------------|
| S15 | 117 | (@ad<="20021118") and (nanowire or nanotube or nanostructure) and semiconductor and etch\$4 and mask and ((anodically or electrochemical\$4) with etch\$4) | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/28 17:21 |
| S16 | 14  | ("2001/0054709").URPN.   | USPAT   | OR | ON | 2006/03/28 17:31 |
| S17 | 14  | ("2001/0054709").URPN.   | USPAT   | OR | ON | 2006/03/28 17:33 |
| S18 | 14  | ("2001/0054709").URPN.   | USPAT   | OR | ON | 2006/03/28 17:34 |
| S19 | 257 | nanowires and oxidation and etch   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 05:55 |
| S20 | 25  | "5607876"  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 08:31 |
| S21 | 14  | (@ad<="20021118") and nanowires and semiconductor and dispersion and vibration   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 09:58 |
| S22 | 65  | (@ad<="20021118") and nanowires and semiconductor and dispersion and (vibrat\$4 or ultrasonic or ulta or remov\$4)   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 10:03 |
| S23 | 24  | (@ad<="20021118") and nanowires and semiconductor and dispersion and (vibrat\$4 or ultrasonic or ulta)   | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 11:11 |
| S24 | 27  | (@ad<="20021118") and nanowires and sol-gel  | US-PGPUB;<br>USPAT;<br>USOCR;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | OR | ON | 2006/03/29 13:39 |